# **STARPOWER**

#### **SEMICONDUCTOR**

## **FRED**

# FD400HCH60C8S

600V/400A 4 in one-package

### **General Description**

STARPOWER Diode Power Module provides low Forward voltage as well as low reverse recovery loss. They are designed for the applications such as SMPS.

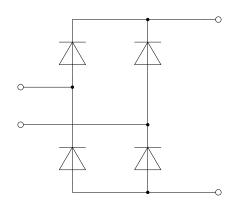
#### **Features**

- Fast soft diode
- Low forward voltage drop
- Small temperature coefficient
- Low reverse recovery losse
- High ruggedness
- Low inductance
- Isolated copper baseplate using DBC technology

## **Typical Applications**

- SMPS
- PFC
- Welding machine

## **Equivalent Circuit Schematic**





# Absolute Maximum Ratings $T_C$ =25°C unless otherwise noted

#### **Diode**

Symbol	Description	Value	Unit
$V_{RRM}$	Repetitive Peak Reverse Voltage	600	V
$V_{RSM}$	Non-repetitive Peak Reverse Voltage	650	V
$I_{\rm F}$	Diode Continuous Forward Current	400	A
$P_{D}$	Maximum Power Dissipation @ T <sub>i</sub> =150°C	706	W

#### Module

Symbol	Description	Value	Unit
$T_{imax}$	Maximum Junction Temperature	150	°C
T <sub>jop</sub>	Operating Junction Temperature	-40 to +125	°C
$T_{STG}$	Storage Temperature Range	-40 to +125	°C
$V_{\rm ISO}$	Isolation Voltage RMS,f=50Hz,t=1min	2500	V

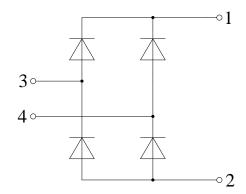
## **Diode Characteristics** T<sub>C</sub>=25°C unless otherwise noted

Symbol	Parameter	Test Conditions	Min.	Тур.	Max.	Unit
$V_{\rm F}$	Diode Forward	$I_F = 400A, T_i = 25^{\circ}C$		1.38	1.80	V
	Voltage	$I_F = 400A, T_j = 125^{\circ}C$		1.41		V
$Q_{r}$	Recovered Charge			15.5		μC
$I_{RM}$	Peak Reverse	V -200VI -400A		265		Α
	Recovery Current	$V_R$ =300V, $I_F$ =400A, -di/dt=7000A/ $\mu$ s, $T_i$ =25°C		203		A
E <sub>rec</sub>	Reverse Recovery	-di/dt=/000A/μs,1 <sub>j</sub> =23 C		3.5		mJ
	Energy			3.3		1113
$Q_{r}$	Recovered Charge			28.5		μC
$I_{RM}$	Peak Reverse	$V_R = 300V, I_F = 400A,$		335		Α
	Recovery Current	$-di/dt=7000A/\mu s, T_j=125^{\circ}C$		333		A
E <sub>rec</sub>	Reverse Recovery			7.5		mJ
	Energy			7.5		1113

## Module Characteristics $T_C=25$ °C unless otherwise noted

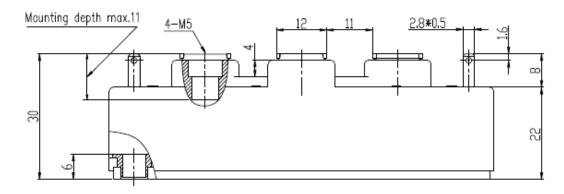
Symbol	Parameter	Min.	Тур.	Max.	Unit
$R_{thJC}$	Junction-to-Case			0.177	K/W
$R_{thCH}$	Case-to-Heatsink		0.046		K/W
M	Terminal Connection Torque, Screw M5	2.5		5.0	N.m
	Mounting Torque, Screw M6	3.0		5.0	
G	Weight of Module		200		g

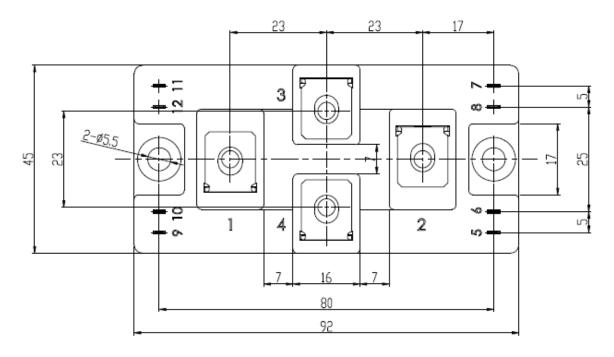
## **Circuit Schematic**



# **Package Dimensions**

#### Dimensions in Millimeters





### **Terms and Conditions of Usage**

The data contained in this product datasheet is exclusively intended for technically trained staff. you and your technical departments will have to evaluate the suitability of the product for the intended application and the completeness of the product data with respect to such application.

This product data sheet is describing the characteristics of this product for which a warranty is granted. Any such warranty is granted exclusively pursuant the terms and conditions of the supply agreement. There will be no guarantee of any kind for the product and its characteristics.

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Should you intend to use the Product in aviation applications, in health or live endangering or life support applications, please notify.

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